Features

- Medium-voltage and Standard-voltage Operation
 2.7 (V_{CC} = 2.7V to 5.5V)
- Automotive Temperature Range –40°C to +125°C
- User Selectable Internal Organization
 - 16K: 2048 x 8 or 1024 x 16
- 3-wire Serial Interface
- Sequential Read Operation
- Schmitt Trigger, Filtered Inputs for Noise Suppression
- 2 MHz Clock Rate (5V) Compatibility
- Self-timed Write Cycle (10 ms max)
- High Reliability
 - Endurance: 1 Million Write Cycles
 - Data Retention: 100 Years
- Lead-Free/Halogen-Free Devices Available
- 8-lead JEDEC SOIC and 8-lead TSSOP Packages

Description

The AT93C86A provides 16384 bits of serial electrically erasable programmable read only memory (EEPROM), organized as 1024 words of 16 bits each when the ORG pin is connected to V_{CC} and 2048 words of 8 bits each when it is tied to ground. The device is optimized for use in many automotive applications where low-power and low-voltage operations are essential. The AT93C86A is available in space saving 8-lead JEDEC SOIC and 8-lead TSSOP packages.

Table 1. Pin Configuration

Pin Name	Function
CS	Chip Select
SK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
GND	Ground
VCC	Power Supply
ORG	Internal Organization
DC	Don't Connect

8-lead SOIC

CS 🗀	1	8	
SK 🗔	2	7	
DI 🕅	3	6	🗌 ORG
DO 🖂	4	5	GND

8-lead TSSOP

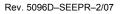
CS 🖂	1	
SK 🗔	2	7 🗖 DC
DI 🗔	3	6 🗀 ORG
DO 🗆	4	5 GND



Three-wire Automotive Temperature Serial EEPROM

16K (2048 x 8 or 1024 x 16)

AT93C86A







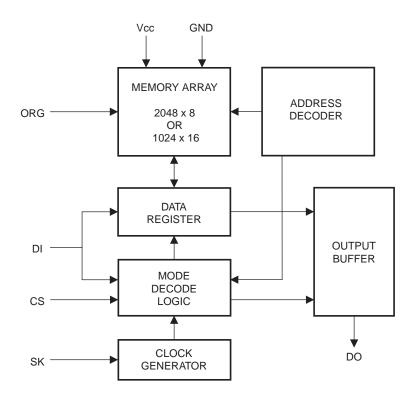
The AT93C86A is enabled through the Chip Select pin (CS), and accessed via a threewire serial interface consisting of Data Input (DI), Data Output (DO), and Shift Clock (SK). Upon receiving a Read instruction at DI, the address is decoded and the data is clocked out serially on the data output pin DO. The write cycle is completely self-timed and no separate erase cycle is required before Write. The write cycle is only enabled when the part is in the Erase/Write Enable state. When CS is brought "high" following the initiation of a write cycle, the DO pin outputs the Ready/Busy status of the part. The AT93C86A is available in a 2.7V to 5.5V version.

Absolute Maximum Ratings*

Operating Temperature–55°C to +125°C
Storage Temperature65°C to +150°C
Voltage on any Pin with Respect to Ground–1.0V to +7.0V
Maximum Operating Voltage 6.25V
DC Output Current 5.0 mA

*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Figure 1. Block Diagram



Note: When the ORG pin is connected to Vcc, the x 16 organization is selected. When it is connected to ground, the x 8 organization is selected. If the ORG pin is left unconnected and the application does not load the input beyond the capability of the internal 1 Meg ohm pullup, then the x 16 organization is selected.

Table 2. Pin Capacitance⁽¹⁾

	a susting a second of the second	-0000 f - 40 MU - V	<pre>'CC = +5.0V (unless otherwise noted</pre>	-1
Applicable over recommended o	nerating range from 1.	$= 25^{\circ}$ $T = 10000007$	$r_{ab} = \pm 5 \text{ UV} \text{ (Unless otherwise note:}$	11
		= 250, 1 = 1.000000000000000000000000000000000		

Symbol	Test Conditions	Max	Units	Conditions
C _{OUT}	Output Capacitance (DO)	5	pF	V _{OUT} = 0V
C _{IN}	Input Capacitance (CS, SK, DI)	5	pF	V _{IN} = 0V

Note: 1. This parameter is characterized and is not 100% tested.

Table 3. DC Characteristics

Applicable over recommended operating range from: $T_A = -40^{\circ}C$ to $+125^{\circ}C$, $V_{CC} = +2.7V$ to +5.5V (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Тур	Max	Unit
V _{CC1}	Supply Voltage			2.7		5.5	V
V _{CC2}	Supply Voltage			4.5		5.5	V
1	Cumply Cumpet	$\lambda = 5.0 \lambda$	READ at 1.0 MHz		0.5	2.0	mA
I _{CC}	Supply Current	$V_{\rm CC} = 5.0 V$	WRITE at 1.0 MHz		0.5	2.0	mA
I _{SB1}	Standby Current	V _{CC} = 2.7V	CS = 0V		6.0	10.0	μA
I _{SB2}	Standby Current	V _{CC} = 5.0V	CS = 0V		17	30	μA
I	Input Leakage	$V_{IN} = 0V$ to V_{CC}			0.1	3.0	μA
I _{OL}	Output Leakage	$V_{IN} = 0V$ to V_{CC}			0.1	3.0	μA
V _{IL1} ⁽¹⁾	Input Low Voltage			0.6		0.8	V
$V_{IH1}^{(1)}$	Input High Voltage	$2.7V \leq V_{CC} \leq 5.5V$		2.0		V _{CC} + 1	V
V _{OL1}	Output Low Voltage		I _{OL} = 2.1 mA			0.4	V
V _{OH1}	Output High Voltage	$2.7V \leq V_{CC} \leq 5.5V$	I _{OH} = -0.4 mA	2.4			V

Note: 1. V_{IL} min and V_{IH} max are reference only and are not tested.





Table 4. AC Characteristics

Applicable over recommended operating range from $T_A = -40$ °C to +125 °C, V_{CC} = As Specified, CL = 1 TTL Gate and 100 pF (unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Тур	Max	Units
f _{SK}	SK Clock Frequency	$\begin{array}{l} 4.5V \leq V_{CC} \ \leq 5.5V \\ 2.7V \leq V_{CC} \ \leq 5.5V \end{array}$		0 0		2 1	MHz
t _{sкн}	SK High Time	$\begin{array}{l} 4.5V \leq V_{CC} \ \leq 5.5V \\ 2.7V \leq V_{CC} \ \leq 5.5V \end{array}$		250 250			ns
t _{SKL}	SK Low Time	$\begin{array}{l} 4.5V \leq V_{CC} \ \leq 5.5V \\ 2.7V \leq V_{CC} \ \leq 5.5V \end{array}$		250 250			ns
t _{cs}	Minimum CS Low Time	$\begin{array}{l} 4.5V \leq V_{CC} \ \leq 5.5V \\ 2.7V \leq V_{CC} \ \leq 5.5V \end{array}$		250 250			ns
t _{css}	CS Setup Time	Relative to SK	$\begin{array}{c} 4.5V \leq V_{CC} \ \leq 5.5V \\ 2.7V \leq V_{CC} \ \leq 5.5V \end{array}$	50 50			ns
t _{DIS}	DI Setup Time	Relative to SK	$\begin{array}{l} 4.5V \leq V_{CC} \ \leq 5.5V \\ 2.7V \leq V_{CC} \ \leq 5.5V \end{array}$	100 100			ns
t _{CSH}	CS Hold Time	Relative to SK		0			ns
t _{DIH}	DI Hold Time	Relative to SK	$\begin{array}{l} 4.5V \leq V_{CC} \ \leq 5.5V \\ 2.7V \leq V_{CC} \ \leq 5.5V \end{array}$	100 100			ns
t _{PD1}	Output Delay to '1'	AC Test	$\begin{array}{l} 4.5V \leq V_{CC} \ \leq 5.5V \\ 2.7V \leq V_{CC} \ \leq 5.5V \end{array}$			250 500	ns
t _{PD0}	Output Delay to '0'	AC Test	$\begin{array}{l} 4.5 V \leq V_{CC} \ \leq 5.5 V \\ 2.7 V \leq V_{CC} \ \leq 5.5 V \end{array}$			250 500	ns
t _{sv}	CS to Status Valid	AC Test	$\begin{array}{l} 4.5 V \leq V_{CC} \ \leq 5.5 V \\ 2.7 V \leq V_{CC} \ \leq 5.5 V \end{array}$			250 250	ns
t _{DF}	CS to DO in High Impedance	AC Test CS = V _{IL}	$\begin{array}{c} 4.5 V \leq V_{CC} \\ 2.7 V \leq V_{CC} \\ \leq 5.5 V \\ \end{array} \label{eq:VCC}$			100 150	ns
t _{wP}	Write Cycle Time		$2.7V \leq V_{CC} \leq 5.5V$	0.1	4	10	ms
Endurance ⁽¹⁾	5.0V, 25°C			1M			Write Cycle

Note: 1. This parameter is characterized and is not 100% tested.

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			Add	ress	Da	ata	
Instruction	SB	Op Code	x 8	x 16	x 8	x 16	Comments
READ	1	10	$A_{10} - A_0$	$A_{9} - A_{0}$			Reads data stored in memory, at specified address.
EWEN	1	00	11XXXXXXXXX	11XXXXXXXXX			Write enable must precede all programming modes.
ERASE	1	11	$A_{10} - A_0$	$A_{9} - A_{0}$			Erases memory location $A_n - A_0$.
WRITE	1	01	$A_{10} - A_0$	$A_{9} - A_{0}$	$D_{7} - D_{0}$	$D_{15} - D_0$	Writes memory location $A_n - A_0$.
ERAL	1	00	10XXXXXXXX	10XXXXXXXX			Erases all memory locations. Valid only at V_{CC} = 4.5V to 5.5V.
WRAL	1	00	01XXXXXXXX	01XXXXXXXX	$D_{7} - D_{0}$	D ₁₅ -D ₀	Writes all memory locations. Valid when V_{CC} = 4.5V to 5.5V and Disable Register cleared.
EWDS	1	00	00XXXXXXXX	00XXXXXXXX			Disables all programming instructions.

Table 5. Instruction Set for the AT93C86A

Functional Description

The AT93C86A is accessed via a simple and versatile 3-wire serial communication interface. Device operation is controlled by seven instructions issued by the host processor. *A valid instruction starts with a rising edge of CS* and consists of a Start Bit (logic "1") followed by the appropriate Op Code and the desired memory address location.

READ (READ): The Read (READ) instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the serial output pin DO. Output data changes are synchronized with the rising edges of serial clock SK. It should be noted that a dummy bit (logic "0") precedes the 8- or 16-bit data output string. The AT93C86A supports sequential read operations. The device will automatically increment the internal address pointer and clock out the next memory location as long as CS is held high. In this case, the dummy bit (logic "0") will not be clocked out between memory locations, thus allowing for a continuous stream of data to be read.

ERASE/WRITE (EWEN): To assure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out. Please note that once in the EWEN state, programming remains enabled until an EWDS instruction is executed or V_{CC} power is removed from the part.

ERASE (ERASE): The Erase (ERASE) instruction programs all bits in the specified memory location to the logical "1" state. The self-timed erase cycle starts once the Erase instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). A logic "1" at pin DO indicates that the selected memory location has been erased, and the part is ready for another instruction.

WRITE (WRITE): The Write (WRITE) instruction contains the 8 or 16 bits of data to be written into the specified memory location. The self-timed programming cycle t_{WP} starts after the last bit of data is received at serial data input pin DI. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). A logic "0" at DO indicates that programming is still in progress. A logic "1" indicates that the memory location at the specified address has been written with the





data pattern contained in the instruction and the part is ready for further instructions. A Ready/Busy status cannot be obtained if the CS is brought high after the end of the self-timed programming cycle t_{WP} .

ERASE ALL (ERAL): The Erase All (ERAL) instruction programs every bit in the memory array to the logic "1" state and is primarily used for testing purposes. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). The Eral instruction is valid only at V_{CC} = 5.0V ± 10%.

WRITE ALL (WRAL): The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of 250 ns (t_{CS}). The Wral instruction is valid only at V_{CC} = 5.0V ± 10%.

ERASE/WRITE DISABLE (EWDS): To protect against accidental data disturbance, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the Read instruction is independent of both the Ewen and Ewds instructions and can be executed at any time.

6

Timing Diagrams

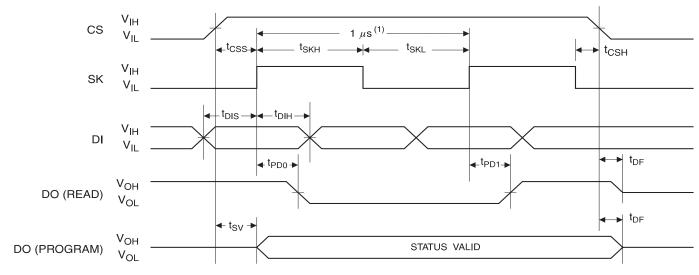


Figure 2. Synchronous Data Timing

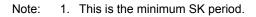
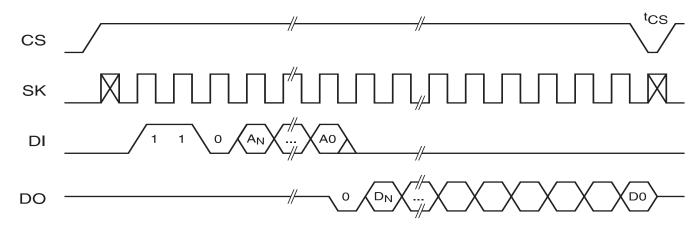


Table 6. Organization Key for Timing Diagrams

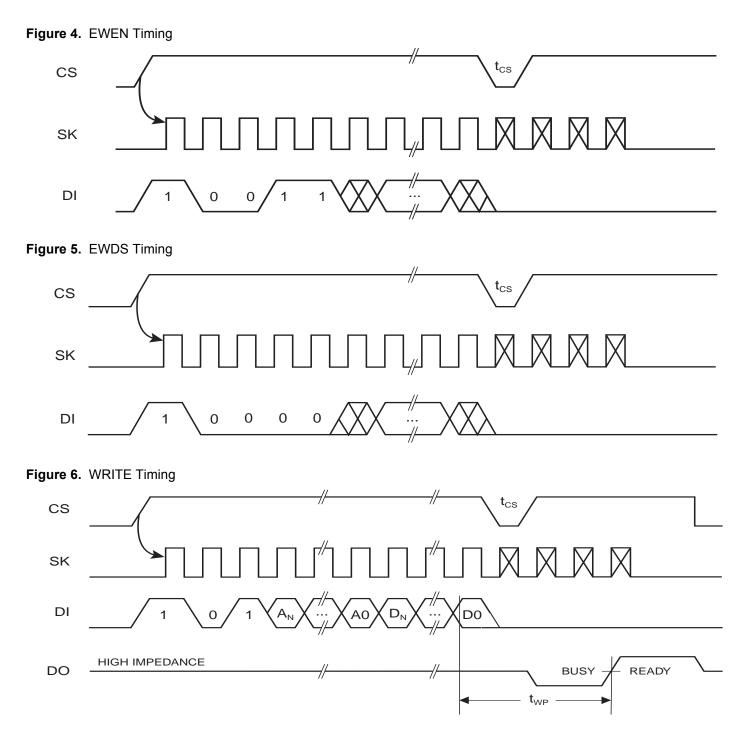
	AT93C86A (16K)				
I/O	x 8	x 16			
A _N	A ₁₀	A ₉			
D _N	D ₇	D ₁₅			



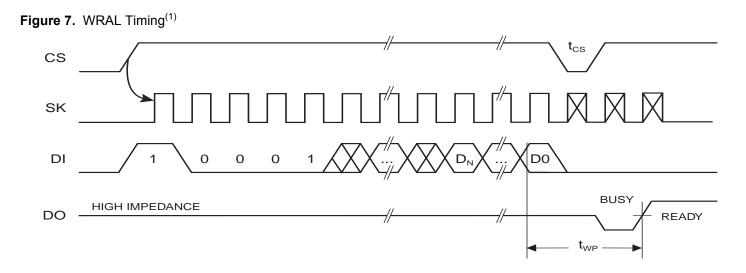






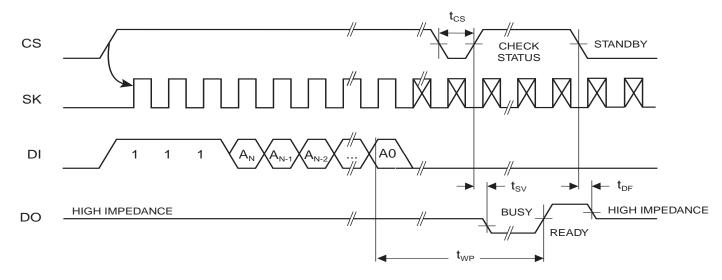


8



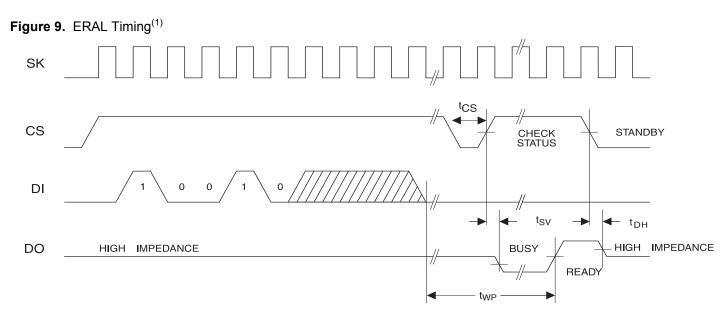
Note: 1. Valid only at V_{CC} = 4.5V to 5.5V.











Note: 1. Valid only at V_{CC} = 4.5V to 5.5V.

AT93C86A Ordering Information

Ordering Code	Package	Operation Range
AT93C86A-10SQ-2.7 AT93C86A-10TQ-2.7	8S1 8A2	Lead-free/Halogen-free Automotive Temperature (–40°C to 125°C)

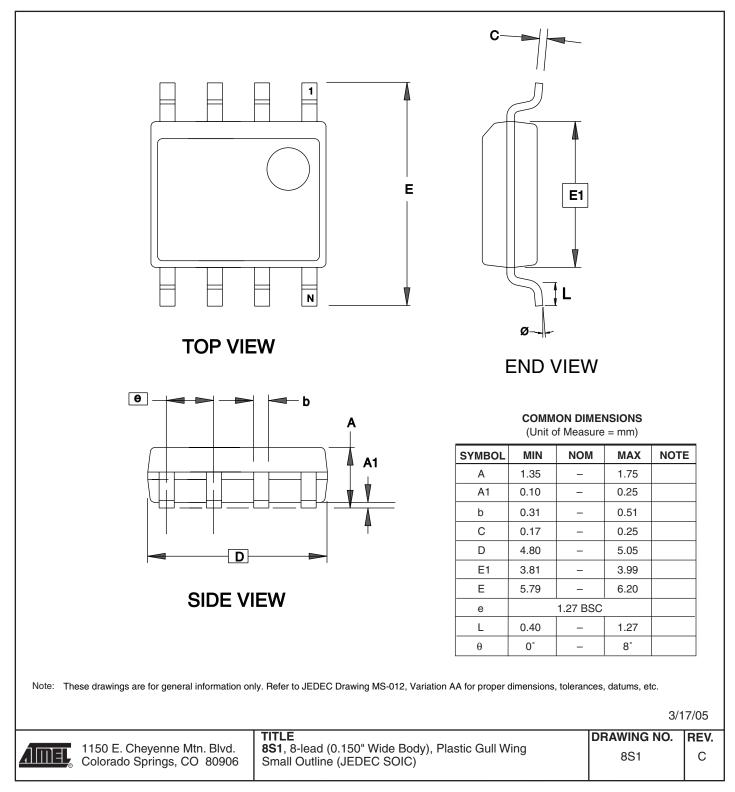
	Package Type				
8S1	8S1 8-lead, 0.150" Wide, Plastic Gull Wing Small Outline (JEDEC SOIC)				
8A2	8A2 8-lead, 0.170" Wide, Thin Shrink Small Outline Package (TSSOP)				
	Options				
-2.7	Low Voltage (2.7V to 5.5V)				



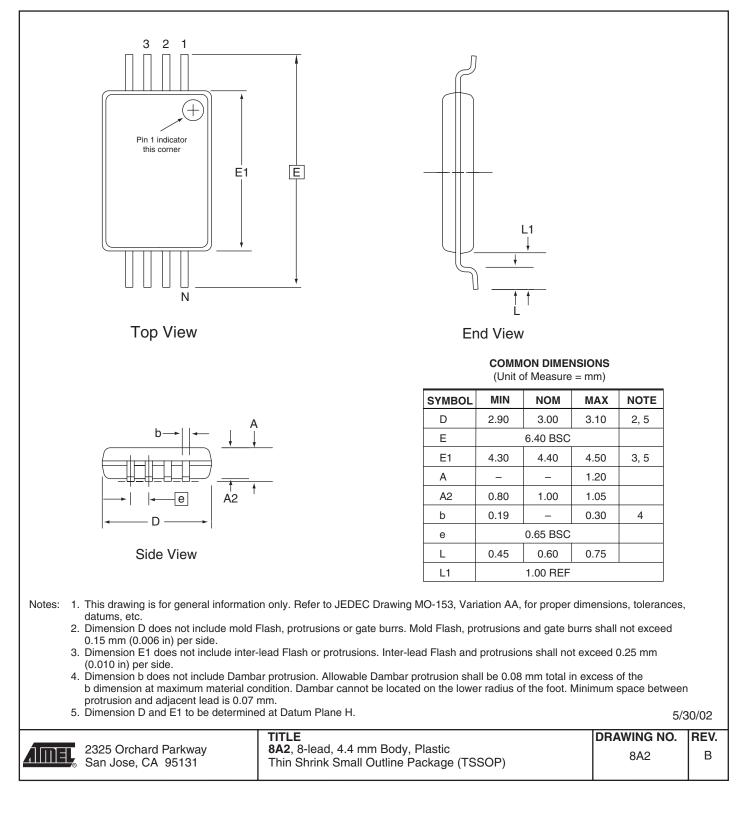


Packaging Information

8S1 – JEDEC SOIC



8A2 – TSSOP







Revision History

Doc. Rev.	Date	Comments
5096D	2/2007	Removed PDIP package offering Removed Pb'd part numbers
5096C	9/2006	Revision history implemented; Removed 'Preliminary' status from datasheet.



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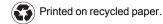
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5096D-SEEPR-2/07